TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74ACT138P,TC74ACT138F,TC74ACT138FN,TC74ACT138FT

3-to-8 Line Decoder

The TC74ACT138 is an advanced high speed CMOS 3-to-8 LINE DECODER fabricated with silicon gate and double-layer metal wiring C2MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

This device may be used as a level converter for interfacing TTL or NMOS to High Speed CMOS. The inputs are compatible with TTL, NMOS and CMOS output voltage levels.

When the device is enabled, 3 Binary Select inputs (A, B and C) determine which one of the outputs $(\overline{Y}0 - \overline{Y}7)$ will go low.

When enable input G1 is held low or either $\overline{G}2A$ or $\overline{G}2B$ is held high, decoding function is inhibited and all outputs go high.

G1, G2A, and G2B inputs are provided to ease cascade connection and for use as an address decoder for memory

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

Features

- High speed: $t_{pd} = 6.0 \text{ ns (typ.)}$ at $V_{CC} = 5 \text{ V}$
- Low power dissipation: $I_{CC} = 8 \mu A \text{ (max)}$ at $T_{a} = 25 \text{°C}$
- Compatible with TTL outputs: $V_{IL} = 0.8 \text{ V (max)}$ $V_{IH} = 2.0 \text{ V (min)}$
- Symmetrical output impedance: | I_{OH} | = I_{OL} = 24 mA (min) Capability of driving 50Ω transmission lines.
- Balanced propagation delays: $t_{pLH} \simeq t_{pHL}$
- Pin and function compatible with 74F138

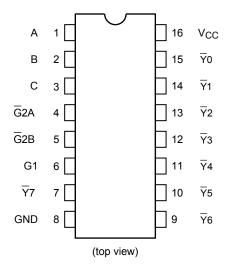
xxxFN (JEDEC SOP) is not available in Note: Japan. TC74ACT138P DIP16-P-300-2.54A TC74ACT138F SOP16-P-300-1.27A SOP16-P-300-1.27 TC74ACT138FN SOL16-P-150-1.27 TC74ACT138FT

TSSOP16-P-0044-0.65A

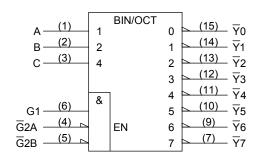
Weight

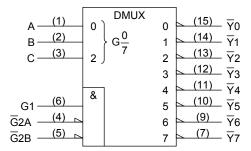
DIP16-P-300-2.54A : 1.00 g (typ.) SOP16-P-300-1.27A : 0.18 g (typ.) SOP16-P-300-1.27 : 0.18 g (typ.) : 0.13 g (typ.) SOL16-P-150-1.27 TSSOP16-P-0044-0.65A: 0.06 g (typ.)

Pin Assignment



IEC Logic Symbol





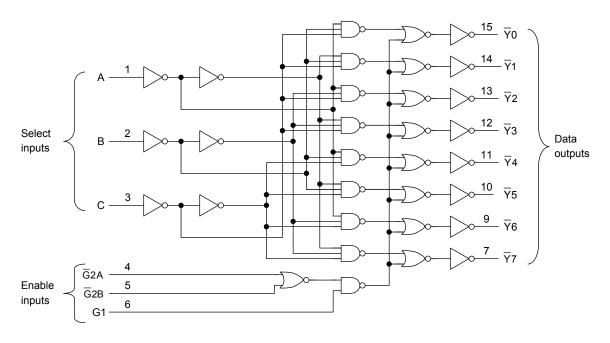
Truth Table

| Inputs | | | | | Outputs | | | | | | | | | |
|--------|------------------|-----|--------|---|---------------------|------------------|------------|--|------------|--|------------|-----------------|--------------------|-------------------------------|
| Enable | | | Select | | <u></u> | <u>\text{Y}1</u> | <u>7</u> 2 | - - - - | <u>7</u> 4 | - - - <u>-</u> | <u>7</u> 6 | - 77 | Selected Output | |
| G1 | G ₂ A | G2B | С | В | Α | 10 | T I | 12 | 13 | 14 | 13 | 10 | 1 7 | · |
| L | Х | Х | Х | Х | Х | Н | Н | Н | Н | Н | Н | Н | Н | None |
| Х | Н | X | X | Х | Х | Н | Н | Н | Η | Н | Н | Н | Н | None |
| Х | Х | Η | X | Х | Х | Н | Н | Н | Η | Н | Н | Н | Н | None |
| Н | L | L | L | L | L | L | Н | Н | Н | Н | Н | Н | Н | <u>\(\bar{Y}\) 0 \\ \} \</u> |
| Н | L | L | L | L | Н | Н | L | Н | Н | Н | Н | Н | Н | Y 1 |
| Н | L | L | L | Н | L | Н | Н | L | Н | Н | Н | Н | Н | ₹2 |
| Н | L | L | L | Н | Н | Н | Н | Н | L | Н | Н | Н | Н | Y 3 |
| Н | L | L | Н | L | L | Н | Н | Н | Н | L | Н | Н | Н | ₹4 |
| Н | L | L | Н | L | Н | Н | Н | Н | Н | Н | L | Н | Н | ₹5 |
| Н | L | L | Н | Н | L | Н | Н | Н | Н | Н | Н | L | Н | ₹6 |
| Н | L | L | Н | Н | Н | Н | Н | Н | Н | Н | Н | Н | L | Y 7 |

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X: Don't care

Logic Diagram



Absolute Maximum Ratings (Note 1)

| Characteristics | Symbol | Rating | Unit |
|------------------------------------|------------------|------------------------------------|------|
| Supply voltage range | V _{CC} | −0.5 to 7.0 | V |
| DC input voltage | V _{IN} | -0.5 to V _{CC} + 0.5 | V |
| DC output voltage | V _{OUT} | -0.5 to V _{CC} + 0.5 | V |
| Input diode current | I _{IK} | ±20 | mA |
| Output diode current | lok | ±50 | mA |
| DC output current | lout | ±50 | mA |
| DC V _{CC} /ground current | Icc | ±200 | mA |
| Power dissipation | PD | 500 (DIP) (Note 2)/180 (SOP/TSSOP) | mW |
| Storage temperature | T _{stg} | −65 to 150 | °C |

Note1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Note2: 500 mW in the range of Ta = -40 to 65°C. From Ta = 65 to 85°C a derating factor of -10 mW/°C should be applied up to 300 mW.

Recommended Operating Conditions (Note)

| Characteristics | Symbol | Rating | Unit |
|--------------------------|------------------|----------------------|------|
| Supply voltage | V _{CC} | 4.5 to 5.5 | V |
| Input voltage | V _{IN} | 0 to V _{CC} | V |
| Output voltage | V _{OUT} | 0 to V _{CC} | ٧ |
| Operating temperature | T _{opr} | −40 to 85 | °C |
| Input rise and fall time | dt/dV | 0 to 10 | ns/V |

Note: The recommended operating conditions are required to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.



Electrical Characteristics

DC Characteristics

| Characteristics | Symbol | Test Condition VCC (V) | | | - | Га = 25°C | | Ta = −40 to 85°C | | Unit | |
|-----------------------------|-----------------|---|--------------------------|--------|------------------|-----------|------|---------------------|------|---|------|
| Characteristics | Зуптыог | | | | | Min | Тур. | Max | Min | Max | Onit |
| High-level input voltage | V _{IH} | | _ | | 4.5 to 5.5 | 2.0 | _ | - | 2.0 | I | ٧ |
| Low-level input voltage | V _{IL} | | _ | | 4.5 to 5.5 | _ | _ | 0.8 | _ | 0.8 | V |
| | V _{OH} | V _{IN} = V _{IH} or V _{IL} | I _{OH} = -50 μA | | 4.5 | 4.4 | 4.5 | _ | 4.4 | _ | |
| High-level output voltage | | | I _{OH} = -24 mA | | 4.5 | 3.94 | _ | _ | 3.80 | _ | V |
| | | | I _{OH} = -75 mA | (Note) | 5.5 | _ | _ | _ | 3.85 | _ | |
| | | V _{IN} | I _{OL} = 50 μA | | 4.5 | _ | 0.0 | 0.1 | _ | 0.1 | |
| Low-level output voltage | V_{OL} | = V _{IH} or | I _{OL} = 24 mA | | 4.5 | _ | _ | 0.36 | _ | 5°C Ur Max Ur 0.8 V 0.8 V 0.1 0.1 0.44 V 1.65 ±1.0 µл | V |
| | | V _{IL} | I _{OL} = 75 mA | (Note) | 5.5 | _ | _ | _ | _ | 1.65 | |
| Input leakage current | I _{IN} | V _{IN} = V _C | C or GND | | 5.5 | _ | _ | ±0.1 | _ | ±1.0 | μΑ |
| | Icc | V _{IN} = V _C | _C or GND | | 5.5 | _ | _ | 8.0 | _ | 80.0 | μΑ |
| Quiescent supply current | I _C | Per input: V _{IN} = 3.4 V Other input: V _{CC} or GND | | | 5.5 | _ | _ | 1.35 | _ | 1.5 | mA |

Note: This spec indicates the capability of driving 50 Ω transmission lines.

One output should be tested at a time for a 10 ms maximum duration.

AC Characteristics ($C_L = 50 \text{ pF}$, $R_L = 500 \Omega$, input: $t_r = t_f = 3 \text{ ns}$)

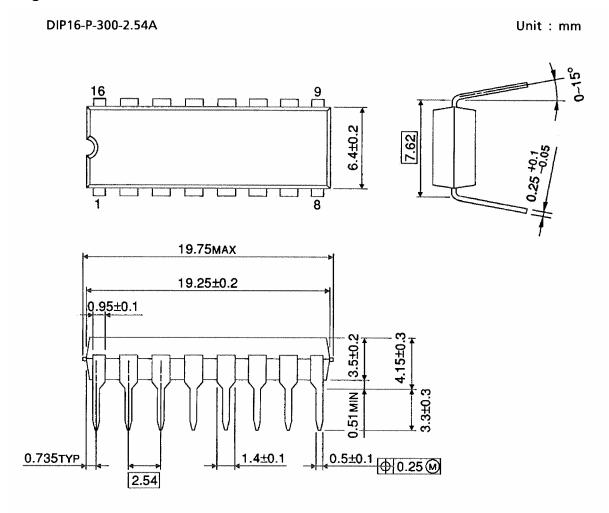
| Characteristics | Symbol | Test Condition | Ta = 25°C | | | Ta = −40 to 85°C | | Unit | |
|---|------------------|----------------|---------------------|-----|------|---------------------|-----|------|----|
| | -, | | V _{CC} (V) | Min | Тур. | Max | Min | Max | |
| Propagation delay time $(A,B,C\text{-}\overline{Y})$ | t _{pLH} | _ | 5.0 ± 0.5 | _ | 6.7 | 10.1 | 1.0 | 11.5 | ns |
| Propagation delay time $(G1-\overline{Y}\)$ | t _{pLH} | _ | 5.0 ± 0.5 | _ | 6.8 | 10.5 | 1.0 | 12.0 | ns |
| Propagation delay time (\$\overline{G}2 - \overline{Y}\$) | t _{pLH} | _ | 5.0 ± 0.5 | _ | 6.9 | 11.0 | 1.0 | 12.5 | ns |
| Input capacitance | C _{IN} | _ | | _ | 5 | 10 | _ | 10 | pF |
| Power dissipation capacitance | C _{PD} | | (Note) | _ | 55 | _ | _ | _ | pF |

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

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Average operating current can be obtained by the equation:

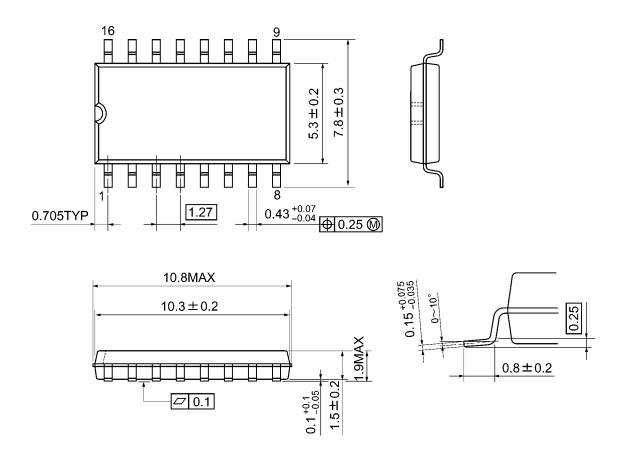
 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$



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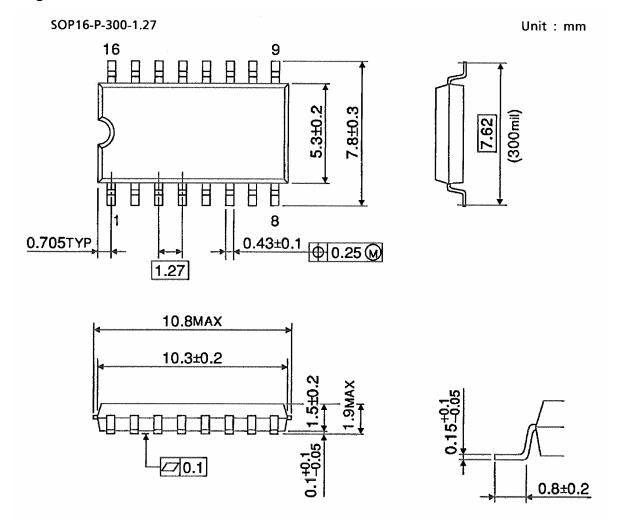
Weight: 1.00 g (typ.)

SOP16-P-300-1.27A Unit: mm



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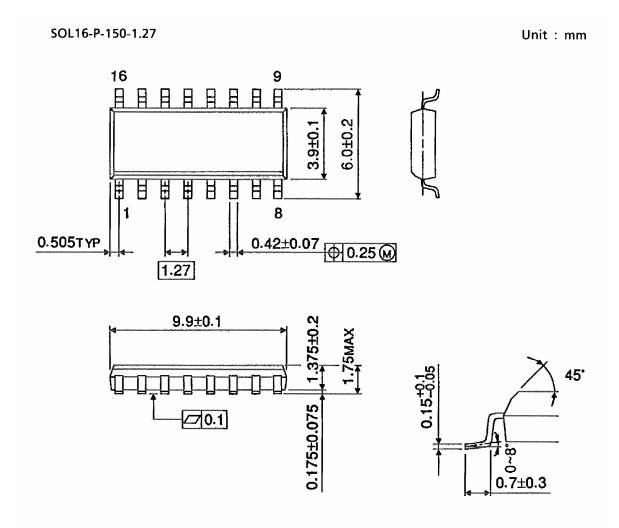
Weight: 0.18 g (typ.)



Weight: 0.18 g (typ.)



Package Dimensions (Note)

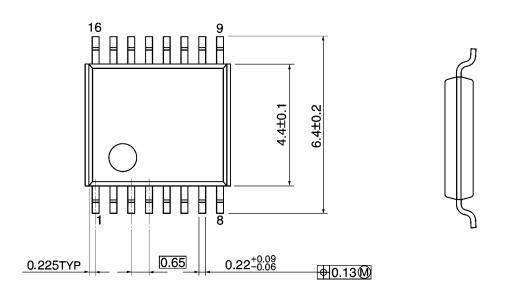


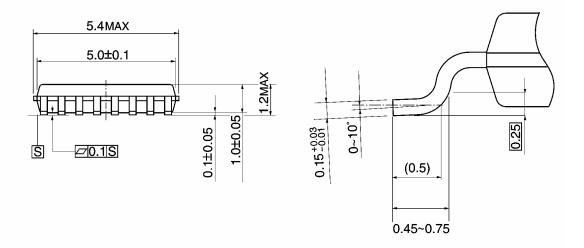
Note: This package is not available in Japan.

Weight: 0.13 g (typ.)

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TSSOP16-P-0044-0.65A Unit: mm





Weight: 0.06 g (typ.)

Note: Lead (Pb)-Free Packages

DIP16-P-300-2.54A SOP16-P-300-1.27A SOL16-P-150-1.27 TSSOP16-P-0044-0.65A

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